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SPECIFICATIONS

1400 nm High Power Superluminescent LED

DL-CS40H2B

DenseLight Semiconductors reserves the right to make product design or specifications changes without notice.

A. PRODUCT DESCRIPTION

The DenseLight DL-CS40H2B series is a broadband SLED that operates in a true inherent superluminescent mode. This superluminescent property generates broader band at higher drive currents in contrast to other conventional SLEDs which are ASE-based, where high drive tends to give narrower band. Its low coherence reduces Rayleigh backscattering noise. Coupled with high power and large spectral width, it offsets photoreceiver noise and improves spatial resolution (in OCT) and measurand sensitivity (in sensors). The SLED is available in 14-pin DIL package. It is compliance with the requirements of Bellcore Document GR-468-CORE.

Enabled by DensePIC™ spread spectra bandgap engineering technology, future generations of DenseLight SLEDs promise higher chip powers (up to 50mW possible), and broader spectral bands (beyond 120nm). Higher levels of integration may feature integrated SLEDs with phase modulators, optical couplers and photodetectors into a complete optical sensor chipset.

For responsive prototyping enquiries please email: info@denselight.com

B. FEATURES

- Ex-fiber output power of >15mW
- 3dB bandwidth of >30nm
- Typical spectral modulation of 0.2dB
- 14-pin DIL package
- Single mode fiber

C. APPLICATIONS

- Fiber Optic Gyroscope
- Optical Test Instrument
- Fiber Optic Sensors
- Fiber Optic Communications
- Optical Coherence Tomography
- Biomedical Imaging Device
- Clinical Healing Equipment

D. ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Min	Max	Unit
Reverse voltage	V_R			2	V
Forward current	I_F			350	mA
Forward voltage	V_F	I_{op}		2.5	V
Case temperature	T_C	I_{op}	-40	65	°C
SLED temperature ¹	T_{SLED}	I_{op}	0	70	°C
Thermoelectric cooler voltage	V_{TEC}			3	V
Thermoelectric cooler current	I_{TEC}			1.8	A
Storage temperature	T_{stg}	Unbiased	-40	85	°C
Storage humidity			5	85	%RH
Electro static discharge (ESD)	V_{ESD}	Human body model		500	V
Lead soldering temperature	S_{temp}			260	°C
Lead soldering time	S_{time}			10	sec

E. SPECIFICATIONS ($T_{SLED} = 25$ °C)

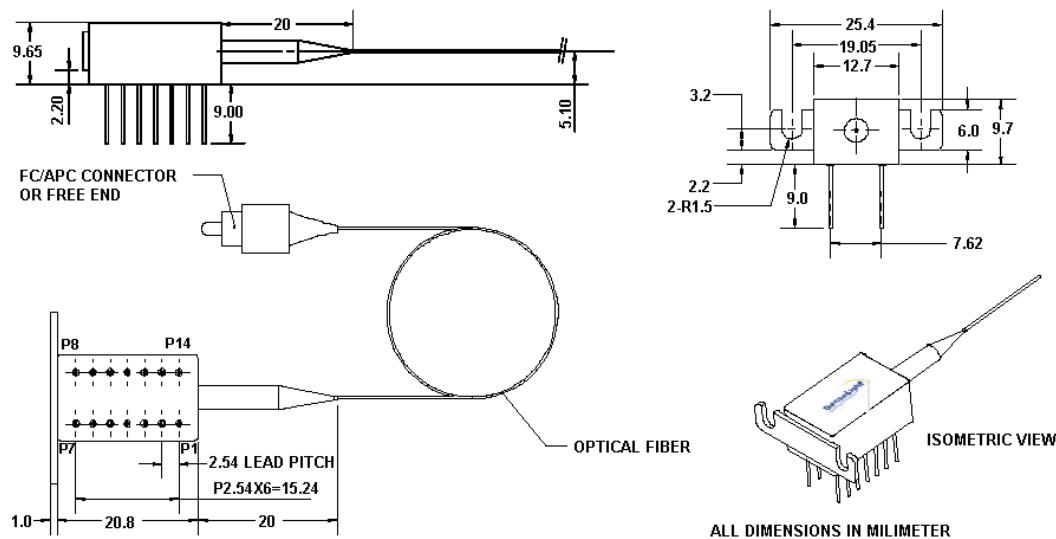
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Operating current	I_{op}				300	mA
Forward voltage	V_F	I_{op}			2	V
Power in SMF	P_o	I_{op}	15			mW
Central wavelength	λ	I_{op}	1380	1400	1420	nm
Bandwidth	B_{FWHM}	I_{op}	30			nm
Spectrum modulation	R	I_{op}		0.2	0.35	dB
Thermistor resistance	R_{therm}	$T = 25$ °C	9.5	10	10.5	kΩ
Thermoelectric cooler voltage	V_{TEC}	I_{op}			2.5	V
Thermoelectric cooler current	I_{TEC}	I_{op}			1.1	A

1 T_{SLED} is monitored by internal thermistor with external pin out.

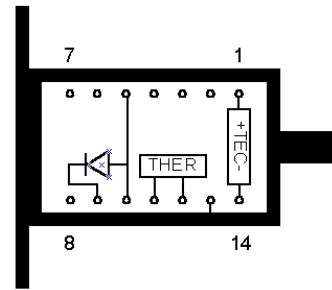
F. PACKAGE

DIL package

Part	Description
Package type	DIL
Fiber:	SMF-28
MFD	10µm
Cladding diameter	125µm
Coating diameter	245µm
Jacket	900µm loose tube
Fiber pigtail length	1m
Fiber bending radius	>40mm
Fiber Connector	FC/APC
Dimensions	See figure

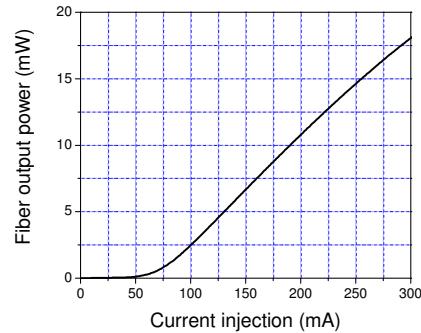


Pin Assignment	
1	TEC+
2	--
3	--
4	--
5	SLED ANODE +
6	--
7	--
8	--
9	SLED CATHODE -
10	SLED ANODE +
11	THERMISTOR
12	THERMISTOR
13	CASE
14	TEC -

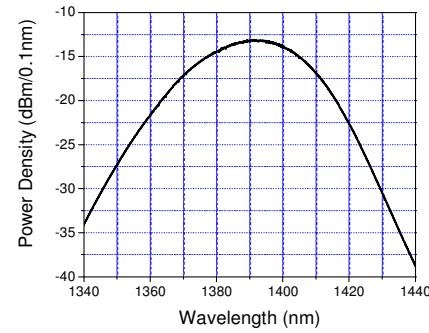


G. TYPICAL PERFORMANCE CHARACTERISTICS

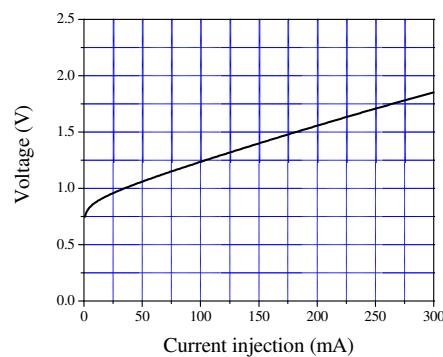
Operating condition: $T_{SLED} = 25^\circ\text{C}$



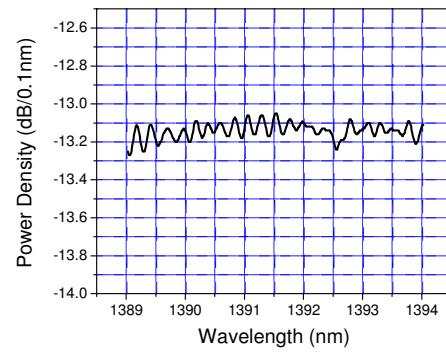
P-I Curve



Spontaneous Emission Spectrum



I-V Curve



Spectrum Modulation